



# 2SA2126

PNP Epitaxial Planar Silicon Transistor

## DC / DC Converter Applications

### Applications

- DC / DC converter, relay drivers, lamp drivers, motor drivers.

### Features

- Adoption of MBIT process.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.

### Specifications

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		-50	V
Collector-to-Emitter Voltage	V <sub>CES</sub>		-50	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		-50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		-6	V
Collector Current	I <sub>C</sub>		-3	A
Collector Current (Pulse)	I <sub>CP</sub>		-6	A
Base Current	I <sub>B</sub>		-600	mA
Collector Dissipation	P <sub>C</sub>		0.8	W
		T <sub>C</sub> =25°C	15	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CB0</sub>	V <sub>CB</sub> =-40V, I <sub>E</sub> =0			-1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =-4V, I <sub>C</sub> =0			-1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =-2V, I <sub>C</sub> =-100mA	200		560	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-500mA		390		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		24		pF

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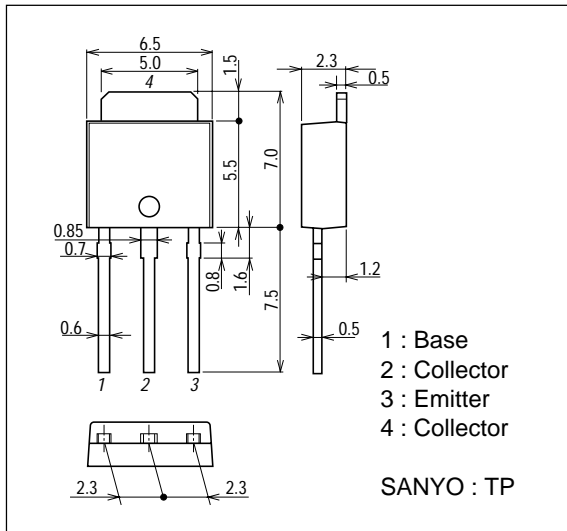
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C = -1A, I_B = -50mA$		-135	-270	mV
	$V_{CE(sat)2}$	$I_C = -2A, I_B = -100mA$		-260	-520	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -2A, I_B = -100mA$		-0.96	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C = -100\mu A, R_{BE} = 0$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu A, I_C = 0$	-6			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		30		ns
Storage Time	$t_{stg}$	See specified Test Circuit.		230		ns
Fall Time	$t_f$	See specified Test Circuit.		18		ns

## Package Dimensions

unit : mm

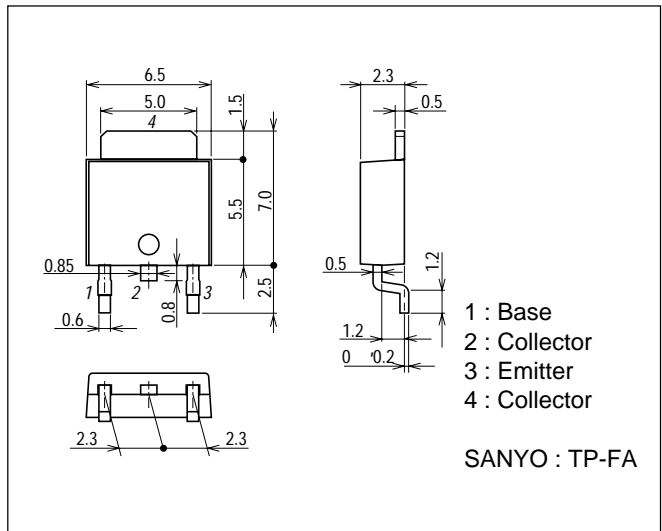
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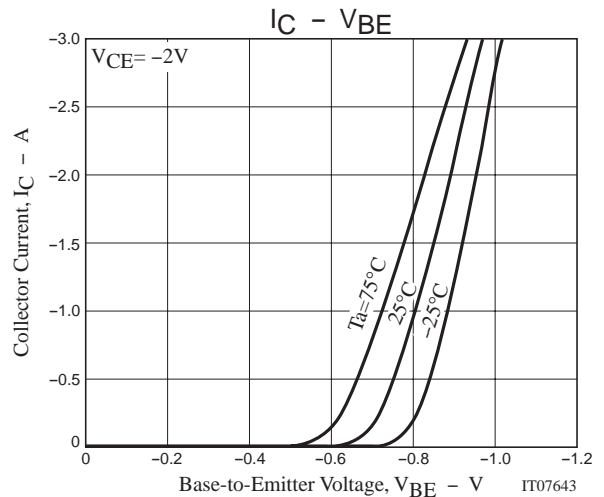
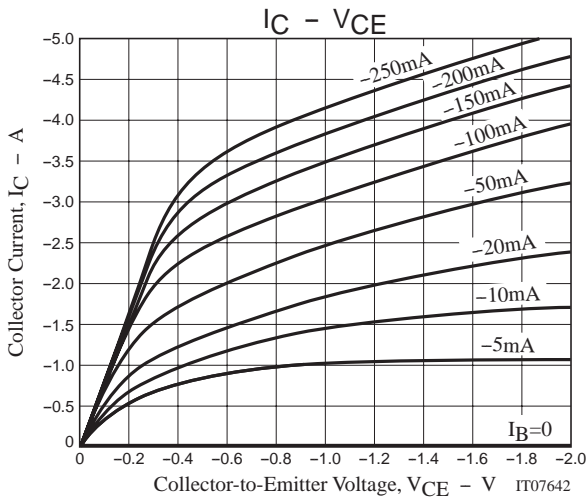
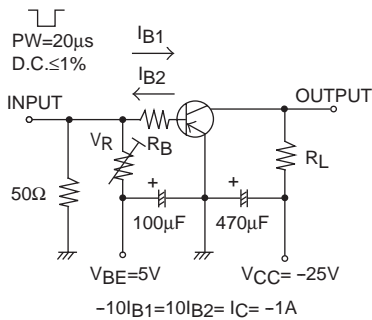
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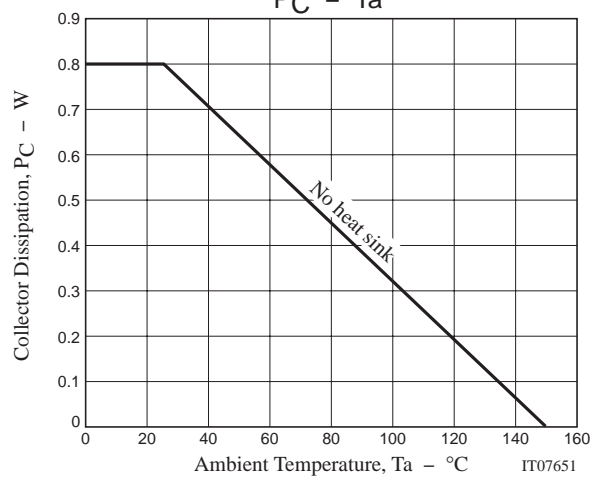
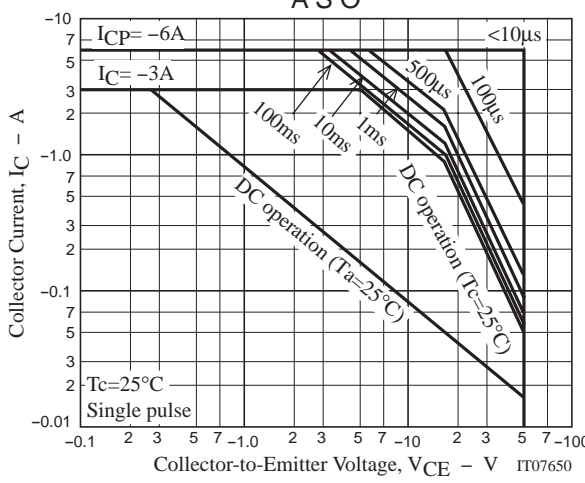
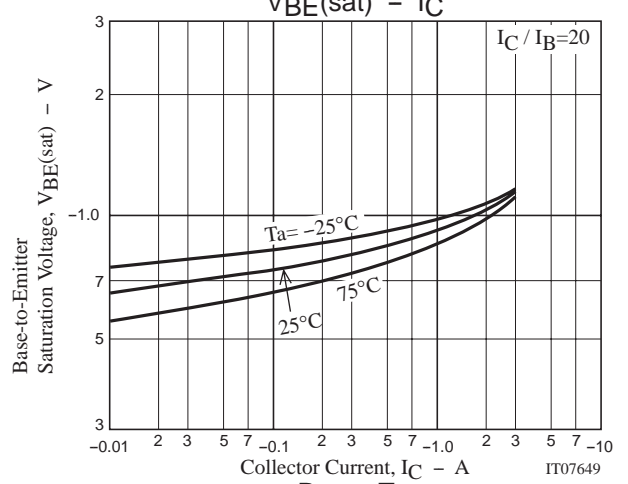
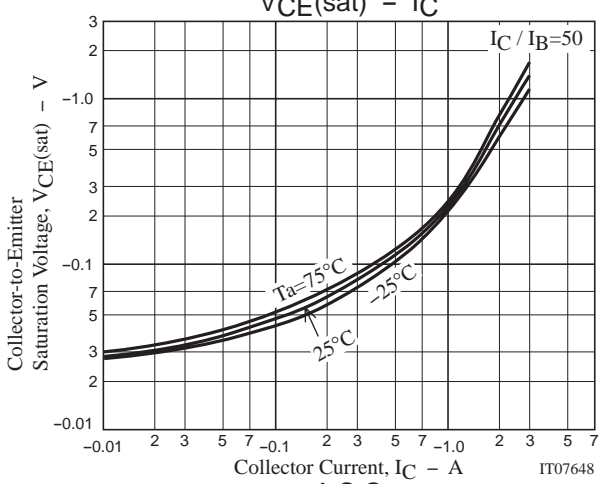
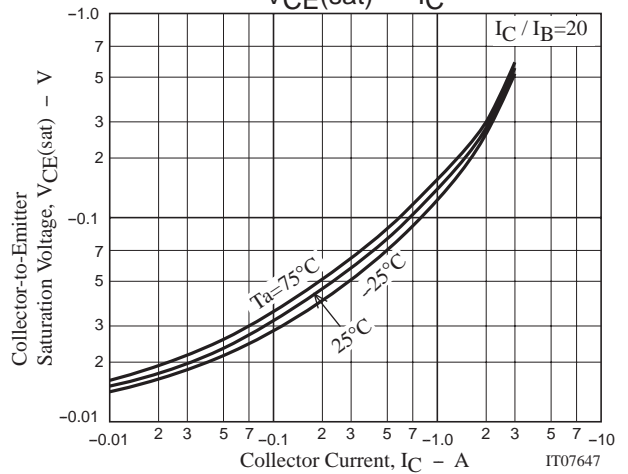
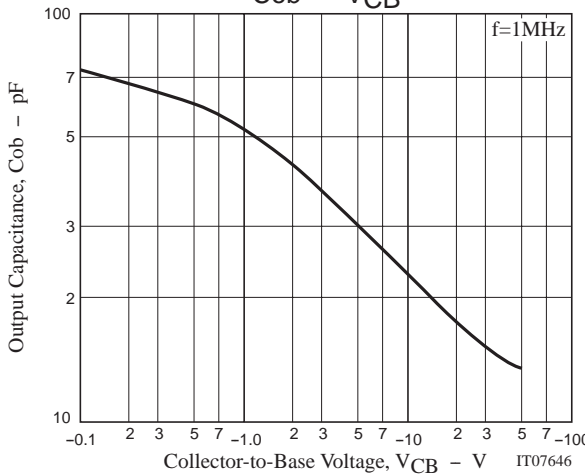
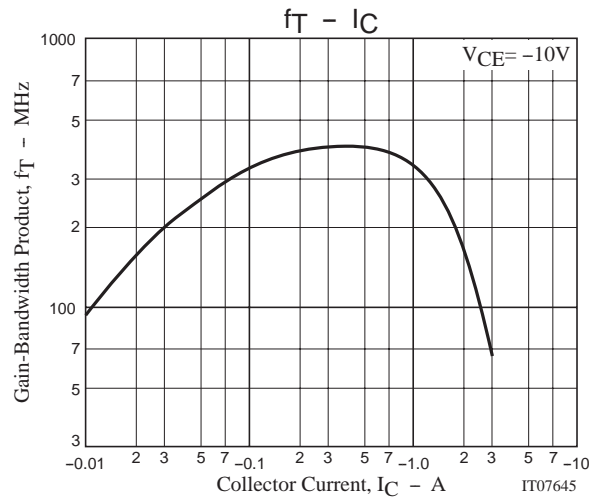
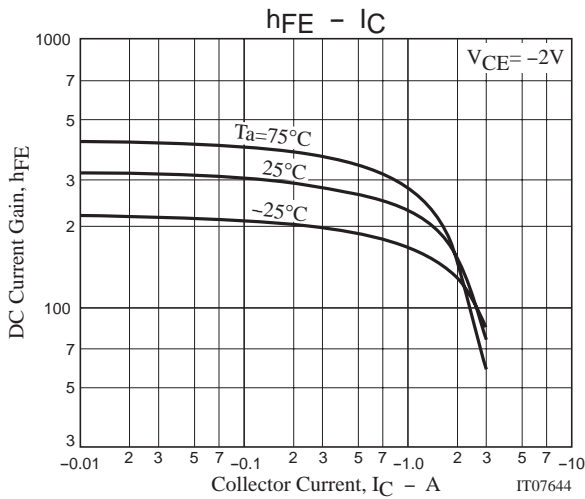
unit : mm

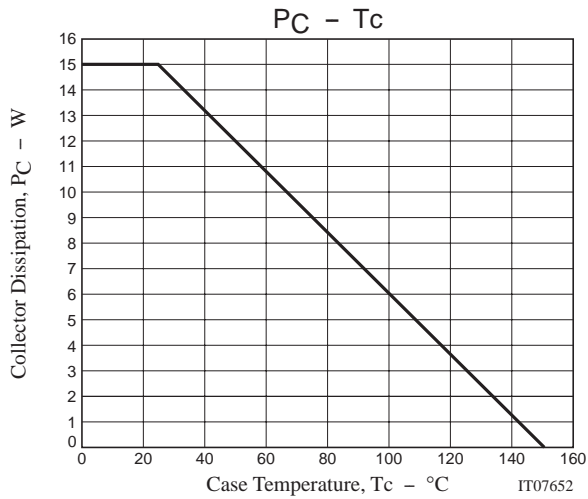
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## Switching Time Test Circuit







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